SQJ110EP

RoHS

COMPLIANT

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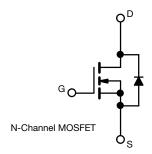
Automotive N-Channel 100 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY	
V _{DS} (V)	100
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.0063
I _D (A)	170
Configuration	Single
Package	PowerPAK SO-8L

FEATURES

- TrenchFET[®] Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Q_{gd}/Q_{gs} ratio < 1 optimizes switching characteristics
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJ110EP (for detailed order number please see <u>www.vishay.com/doc?79776</u>)

ABSOLUTE MAXIMUM RATINGS (T	_C = 25 °C, unles	s otherwise noted)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage Gate-source voltage		V _{DS}	100	V
		V _{GS}	± 20	V
Continuous drain current	T _C = 25 °C	Ŀ	170	
	T _C = 125 °C	I _D	98	
Continuous source current (diode conduction)		I _S	170	А
Pulsed drain current		I _{DM}	224	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	41	
Single pulse avalanche energy		E _{AS}	84	mJ
Maximum power dissipation	T _C = 25 °C	PD	500	w
Maximum power dissipation	T _C = 125 °C	۳D	166	VV V
Operating junction and storage temperature rang	e	TJ, T _{stg}	-55 to +175	- °C
Soldering recommendations (peak temperature) ^t	C		260	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^a	R _{thJA}	42	°C/W
Junction-to-case (drain)		R _{thJC}	0.3	0/10

Notes

a. When mounted on 1" square PCB (FR4 material)

b. See solder profile (<u>www.vishay.com/doc?73257</u>). The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

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SPECIFICATIONS ($T_C = 25 \ ^{\circ}C$,	unless otherv	vise noted)					
PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static					•	•	
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A$		100	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μΑ	2.0	2.7	3.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, $V_{GS} = \pm 20$ V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 100 V	-	- 10		
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 100 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	μA
		$V_{GS} = 0 V$	V _{DS} = 100 V, T _J = 175 °C	-	-	250	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	30	-	-	А
		$V_{GS} = 10 V$	I _D = 15 A	-	0.005	0.0063	
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 10 V$	I _D = 15 A, T _J = 125 °C	-	-	0.0130	Ω
		$V_{GS} = 10 V$	$I_D = 15 \text{ A}, \text{T}_\text{J} = 175 \ ^\circ\text{C}$	-	-	0.0166	
Forward transconductance ^b	9 _{fs}	V _{DS}	= 15 V, I _D = 20 A	-	130	-	S
Dynamic ^b							
Input capacitance	C _{iss}		V _{DS} = 25 V, f = 1 MHz	-	4357	6100	pF
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	473	663	
Reverse transfer capacitance	C _{rss}			-	30	42	
Total gate charge ^c	Qg		V _{DS} = 50 V, I _D = 15 A	-	75	113	nC
Gate-source charge ^c	Q _{gs}	$V_{GS} = 10 V$		-	20	-	
Gate-drain charge ^c	Q _{gd}			-	15	-	
Gate resistance	Rg		f = 1 MHz		0.9	1.40	Ω
Turn-on delay time ^c	t _{d(on)}			-	16	24	
Rise time ^c	t _r		50 V, R _L = 3.33 Ω	-	5	9	
Turn-off delay time ^c	t _{d(off)}	I _D ≅ 15 A,	$I_D \cong 15$ Å, $V_{GEN} = 10$ V, $R_g = 1$ Ω		36	54	ns
Fall time ^c	t _f			-	6	9	1
Source-Drain Diode Ratings and Char	acteristics ^b						
Pulsed current ^a	I _{SM}			-	-	224	А
Forward voltage	V _{SD}	I _F =	I _F = 15 A, V _{GS} = 0 V		-	1.1	V
Body diode reverse recovery time	t _{rr}	I _F = 10 A, di/dt = 100 A/μs		-	48	96	ns
Body diode reverse recovery charge	Q _{rr}			-	83	166	nC
Reverse recovery fall time	t _a			-	33	-	-
Reverse recovery rise time	t _b			-	15	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	3.0	-	А

Notes

a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

b. Guaranteed by design, not subject to production testing

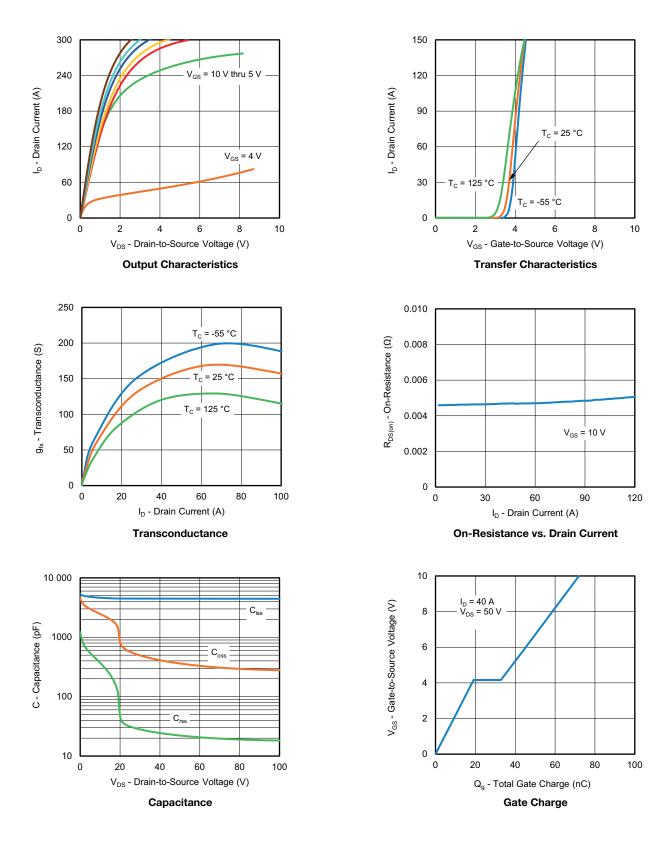
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



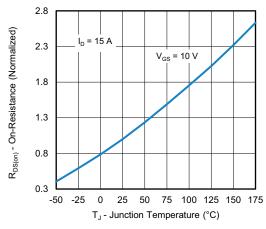
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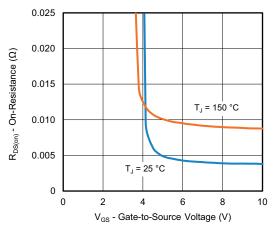
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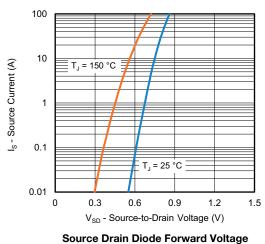
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



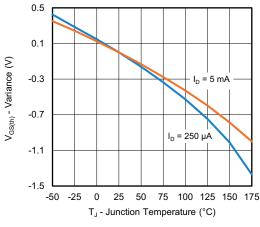
On-Resistance vs. Junction Temperature



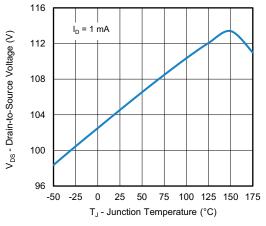
On-Resistance vs. Gate-to Source Voltage



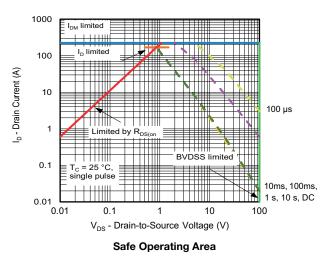
Note



Threshold Voltage



Drain Source Breakdown vs. Junction Temperature



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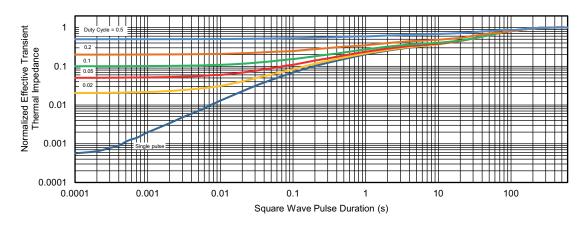
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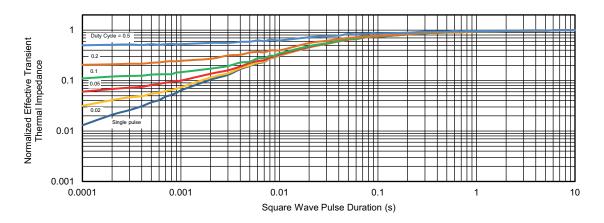
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

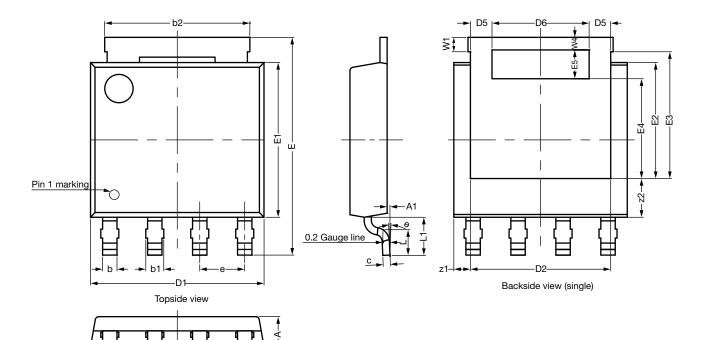
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63151.

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PowerPAK[®] SO-8L (PPKSO8LWLA) Case Outline 3



DIM		MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
А	1.00	1.05	1.10	0.039	0.041	0.043		
A1	0.00		0.127	0.000		0.005		
b	0.33	0.41	0.49	0.013	0.016	0.019		
b1	0.43	0.51	0.59	0.017	0.020	0.023		
b2	4.00	4.10	4.20	0.157	0.161	0.165		
С	0.15	0.20	0.25	0.006	0.008	0.010		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.86	3.96	4.06	0.152	0.156	0.160		
D5	0.51	0.61	0.71	0.020	0.024	0.028		
D6	2.64	2.74	2.84	0.104	0.108	0.112		
е		1.27 BSC		0.050 BSC				
E	6.05	6.15	6.25	0.238	0.242	0.246		
E1	4.27	4.37	4.47	0.168	0.172	0.176		
E2	3.18	3.28	3.38	0.125	0.129	0.133		
E3	3.48	3.58	3.68	0.137	0.141	0.145		
E4	2.72	2.82	2.92	0.107	0.111	0.115		
E5	0.71	0.81	0.91	0.028	0.032	0.036		
L	0.62	0.72	0.82	0.024	0.028	0.032		
L1	0.92	1.07	1.22	0.036	0.042	0.048		
W1	0.31	0.41	0.51	0.012	0.016	0.020		
W4	0.31	0.36	0.41	0.012	0.014	0.016		
z1	0.37	0.47	0.57	0.015	0.019	0.022		
z2	0.99	1.09	1.19	0.039	0.043	0.047		
θ	0°		5°	0°		5°		

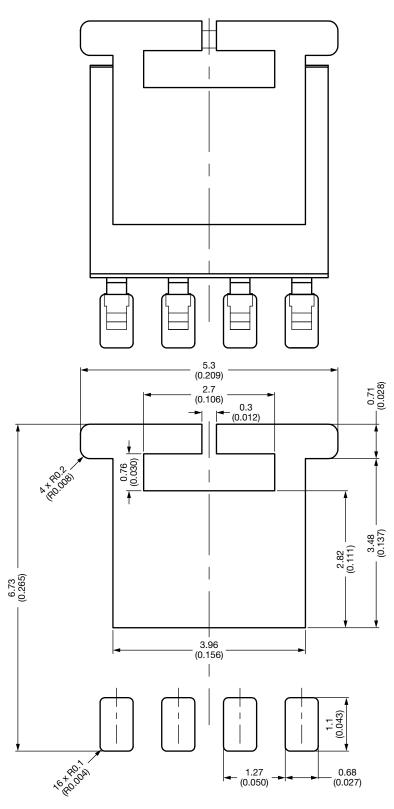
Note

• Millimeter will govern

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Recommended Land Pattern PowerPAK® SO-8L Single Short Ear



Dimensions in Millimeters (Inches)

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